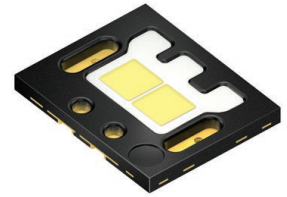


# KW2 HIL532.TK

## OSLON® Black Flat S

The OSLON Black Flat S product family meets both, excellent brightness in combination with outstanding luminance.

The SMT device is very stable, durable and can be used with standard processes. A new solder pad layout allows for high reliability and superior thermal management. The compact chips not only deliver high light output, they are also individually addressable with an ensured chip-to-chip contrast.



## Applications

- Headlamps, LED & Laser & Night Vision

## Features:

- Package: SMD epoxy package
- Chip technology: UX:3
- Typ. Radiation: 120° (Lambertian emitter)
- Color: Cx = 0.325, Cy = 0.345 acc. to CIE 1931 (● ultra white)
- Corrosion Robustness Class: 3B
- Qualifications: AEC-Q102 Qualified with RV-level 1
- ESD: 8 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)
- Color over angle: Better than passus 3.7.2.1 of supplement proposal 7 to ECE reg. 128

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## Ordering Information

Type	Luminous Flux <sup>1)</sup> $I_F = 1000 \text{ mA}$ $\Phi_V$	Ordering Code
KW2 HIL532.TK-D2D9-4L07M0-SC6B	700 ... 980 lm	Q65112A8069

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## Maximum Ratings

Parameter	Symbol		Values
Operating Temperature <sup>2)</sup>	$T_{op}$	min.	-40 °C
		max.	135 °C
Storage Temperature	$T_{stg}$	min.	-40 °C
		max.	135 °C
Junction Temperature	$T_j$	max.	150 °C
Junction Temperature for short time applications*	$T_j$	max.	175 °C
Forward Current $T_s = 25\text{ °C}$	$I_F$	min.	50 mA
		max.	1500 mA
Surge Current $t \leq 10\ \mu\text{s}$ ; $D = 0.005$ ; $T_s = 25\text{ °C}$	$I_{FS}$	max.	2500 mA
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)	$V_{ESD}$		8 kV
Reverse current <sup>3)</sup>	$I_R$	max.	200 mA

\* The median lifetime (L70/B50) for  $T_j = 175\text{ °C}$  is 100h.

## Characteristics

$I_F = 1000 \text{ mA}$ ;  $T_S = 25 \text{ °C}$

Parameter	Symbol		Values
Chromaticity Coordinate <sup>4)</sup>	$C_x$	typ.	0.325
	$C_y$	typ.	0.345
Viewing angle at 50% $I_V$	$2\phi$	typ.	120 °
Forward Voltage <sup>5)</sup> $I_F = 1000 \text{ mA}$	$V_F$	min.	5.60 V
		typ.	6.00 V
		max.	6.75 V
Reverse voltage (ESD device)	$V_{R\text{ESD}}$	min.	45 V
Reverse voltage <sup>3)</sup> $I_R = 20 \text{ mA}$	$V_R$	max.	1.2 V
Chip to Chip Contrast	-	typ.	1:200
Real thermal resistance junction/solderpoint <sup>4)</sup>	$R_{\text{thJS real}}$	typ.	2.3 K / W
		max.	2.8 K / W
Electrical thermal resistance junction/solderpoint <sup>6)</sup> with efficiency $\eta_e = 38 \%$	$R_{\text{thJS elec.}}$	typ.	1.4 K / W
		max.	1.7 K / W

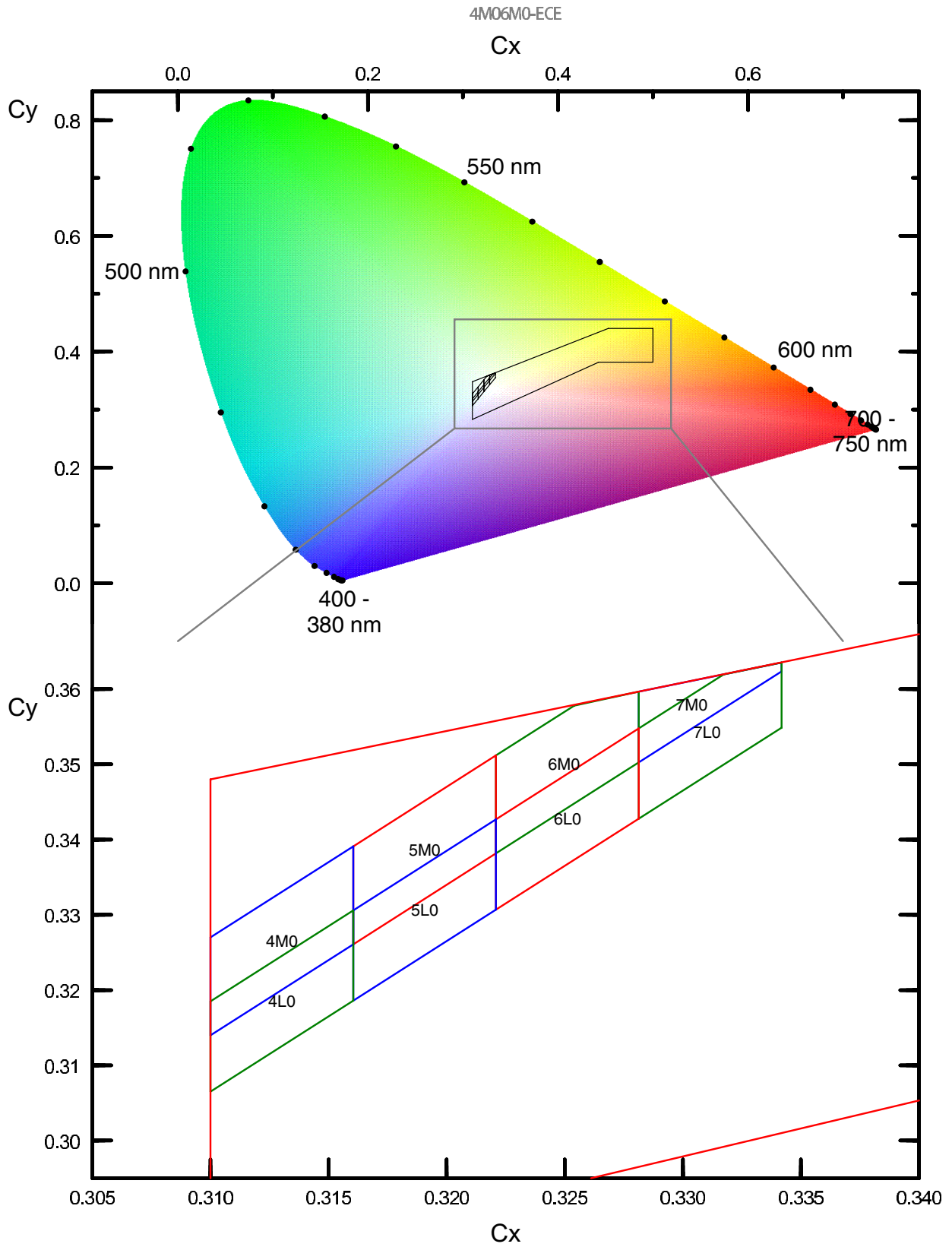
## Brightness Groups

Group	Luminous Flux <sup>1)</sup> $I_F = 1000 \text{ mA}$ min. $\Phi_V$	Luminous Flux <sup>1)</sup> $I_F = 1000 \text{ mA}$ max. $\Phi_V$
D2	700 lm	730 lm
D3	730 lm	760 lm
D4	760 lm	790 lm
D5	790 lm	825 lm
D6	825 lm	860 lm
D7	860 lm	900 lm
D8	900 lm	940 lm
D9	940 lm	980 lm

## Forward Voltage Groups

Group	Forward Voltage <sup>5)</sup> $I_F = 1000 \text{ mA}$ min. $V_F$	Forward Voltage <sup>5)</sup> $I_F = 1000 \text{ mA}$ max. $V_F$
SC	5.60 V	6.20 V
6B	6.20 V	6.75 V

## Chromaticity Coordinate Groups



## Chromaticity Coordinate Groups <sup>4)</sup>

Group	Cx	Cy	Group	Cx	Cy	Group	Cx	Cy
4L0	0.3100	0.3065	5M0	0.3160	0.3261	7L0	0.3281	0.3428
	0.3100	0.3185		0.3160	0.3391		0.3281	0.3548
	0.3160	0.3306		0.3221	0.3512		0.3317	0.3620
	0.3160	0.3186		0.3221	0.3382		0.3342	0.3635
4M0	0.3100	0.3140	6L0	0.3221	0.3307	7M0	0.3281	0.3503
	0.3100	0.3270		0.3221	0.3427		0.3281	0.3597
	0.3160	0.3391		0.3281	0.3548		0.3342	0.3635
	0.3160	0.3261		0.3281	0.3428		0.3342	0.3624
5L0	0.3160	0.3186	6M0	0.3221	0.3382			
	0.3160	0.3306		0.3221	0.3512			
	0.3221	0.3427		0.3254	0.3578			
	0.3221	0.3307		0.3281	0.3597			
				0.3281	0.3503			

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## Group Name on Label

**Example: D2-4L0-6B**

Brightness

Color Chromaticity

Forward Voltage

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D2

4L0

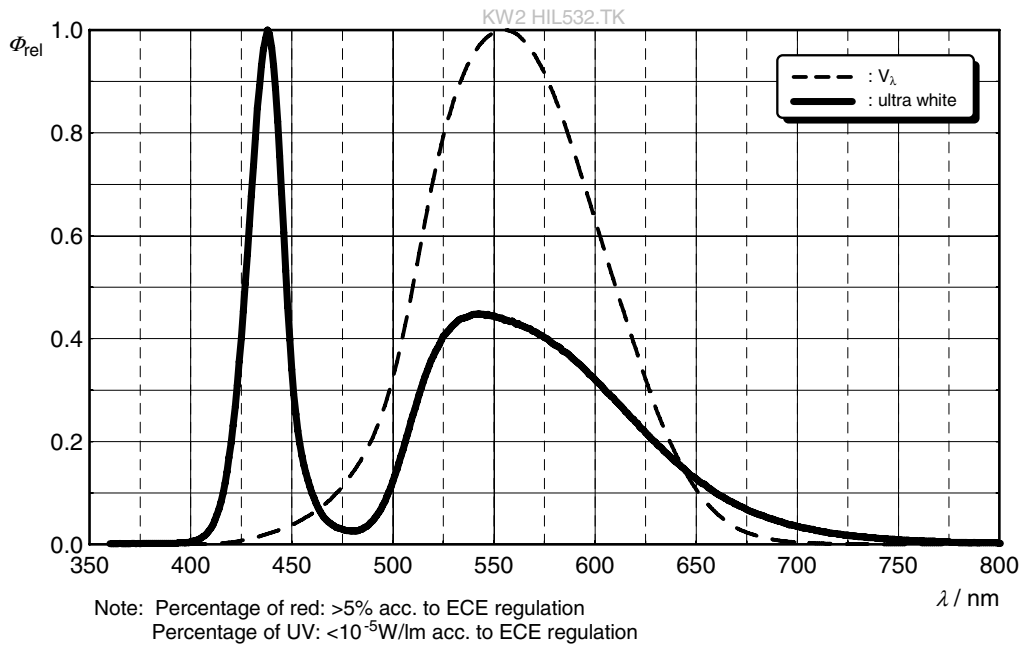
6B

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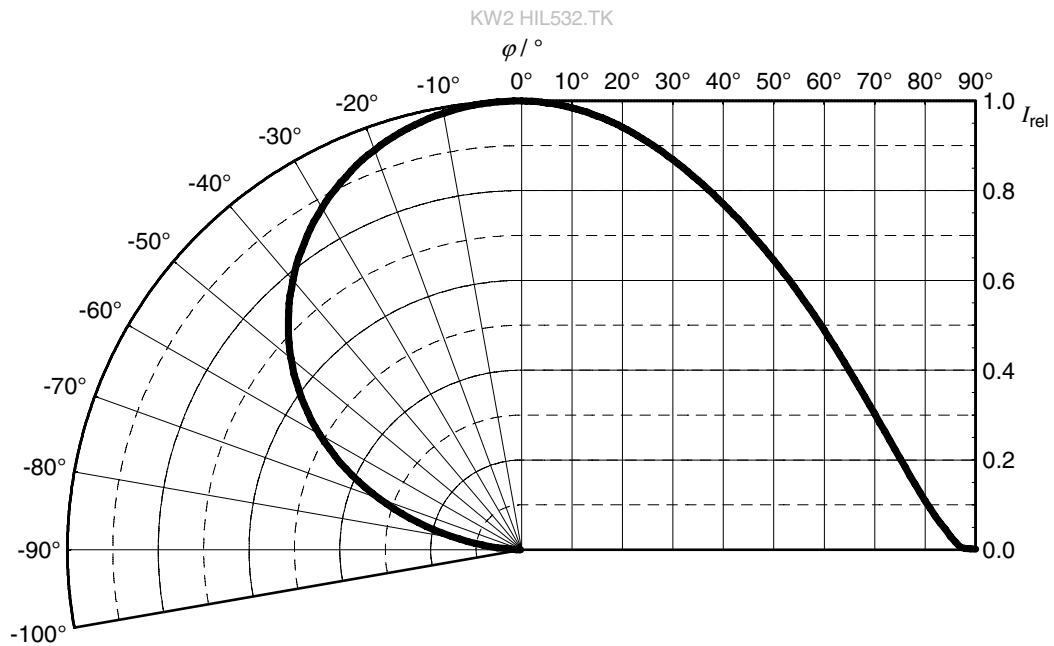
### Relative Spectral Emission <sup>7)</sup>

$\Phi_{rel} = f(\lambda); I_F = 1000 \text{ mA}; T_J = 25 \text{ }^\circ\text{C}$



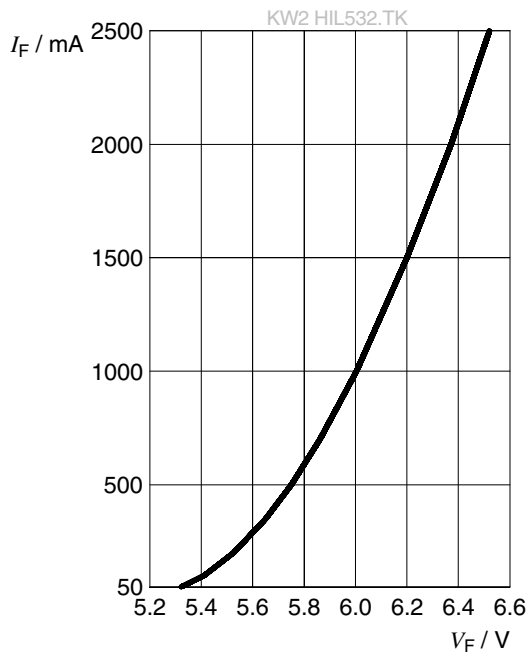
### Radiation Characteristics <sup>7)</sup>

$I_{rel} = f(\phi); T_J = 25 \text{ }^\circ\text{C}$



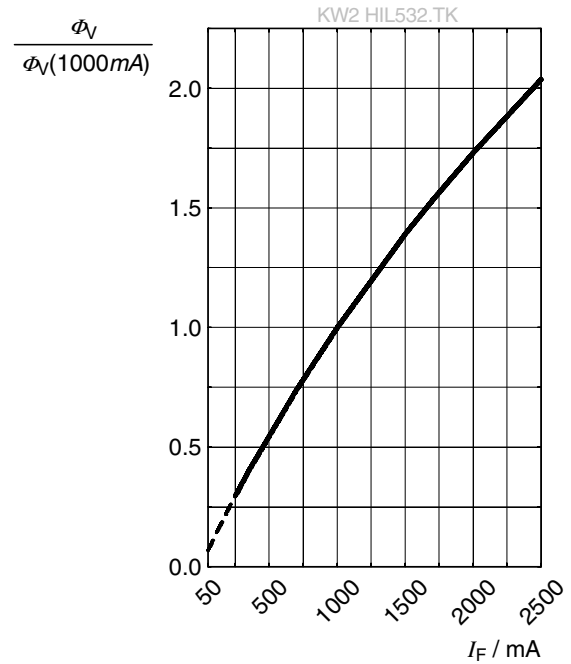
**Forward current** <sup>7)</sup>

$I_F = f(V_F); T_J = 25\text{ °C}$



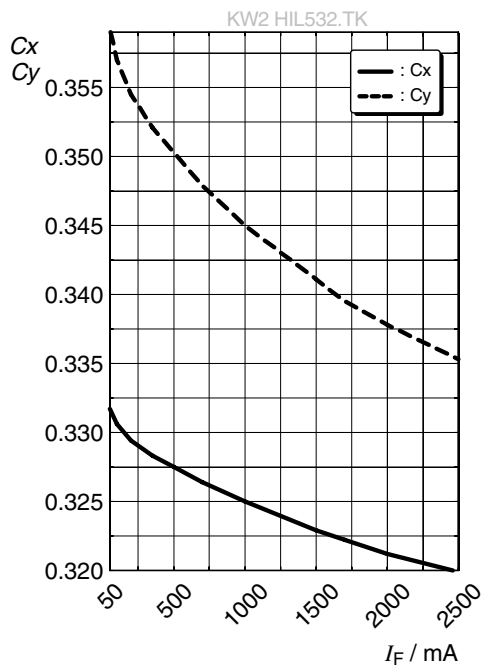
**Relative Luminous Flux** <sup>7), 8)</sup>

$\Phi_V / \Phi_V(1000\text{ mA}) = f(I_F); T_J = 25\text{ °C}$



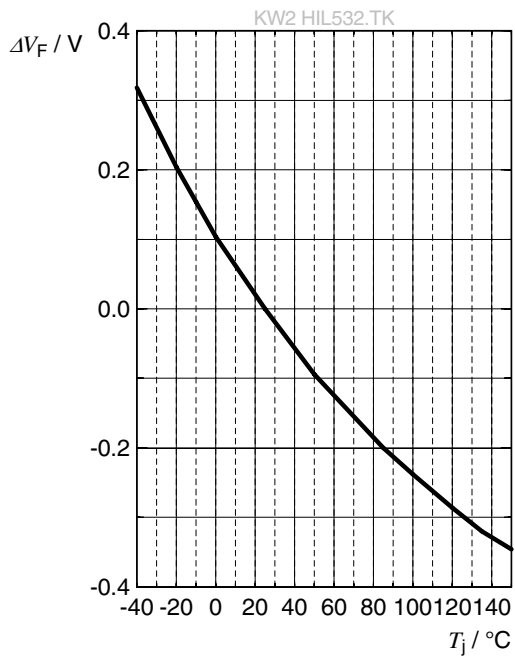
**Chromaticity Coordinate Shift** <sup>7)</sup>

$C_x, C_y = f(I_F); T_J = 25\text{ °C}$



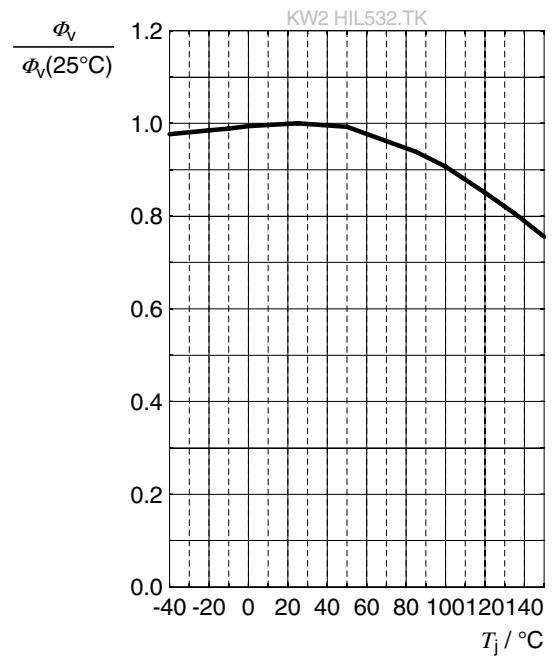
### Forward Voltage <sup>7)</sup>

$$\Delta V_F = V_F - V_F(25\text{ }^\circ\text{C}) = f(T_j); I_F = 1000\text{ mA}$$



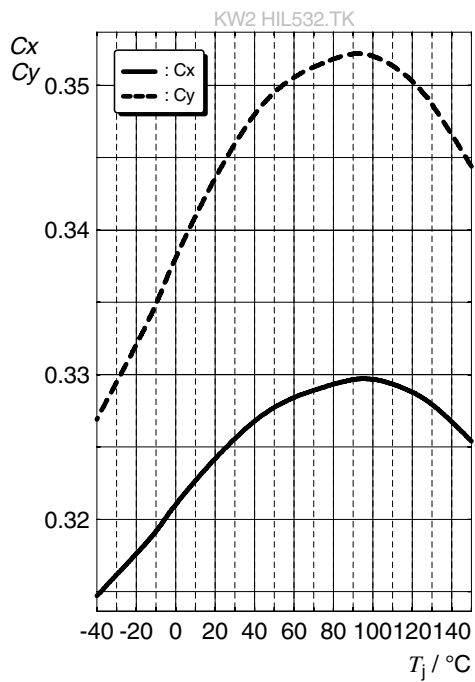
### Relative Luminous Flux <sup>7)</sup>

$$\Phi_v / \Phi_v(25\text{ }^\circ\text{C}) = f(T_j); I_F = 1000\text{ mA}$$



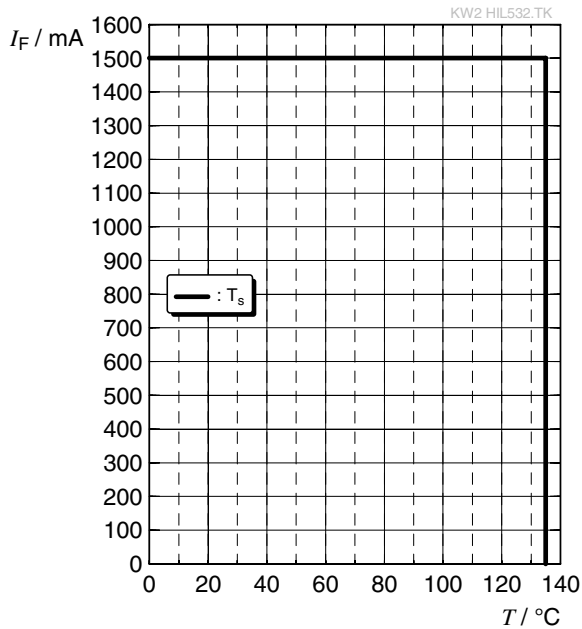
### Chromaticity Coordinate Shift <sup>7)</sup>

$$C_x, C_y = f(T_j); I_F = 1000\text{ mA}$$



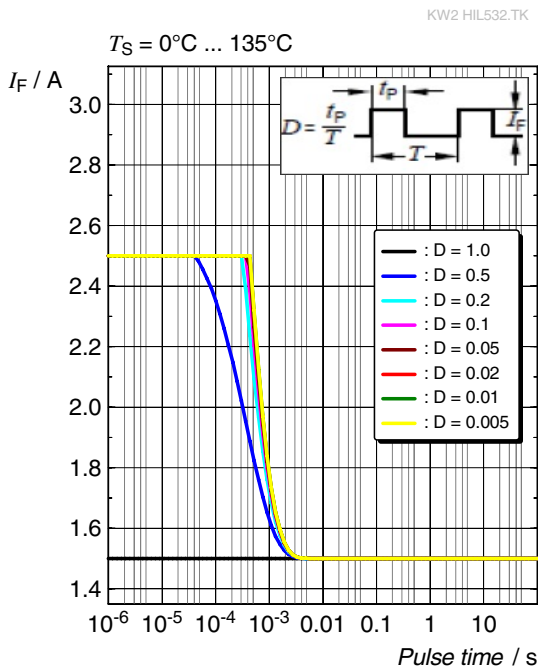
### Max. Permissible Forward Current

$I_F = f(T)$



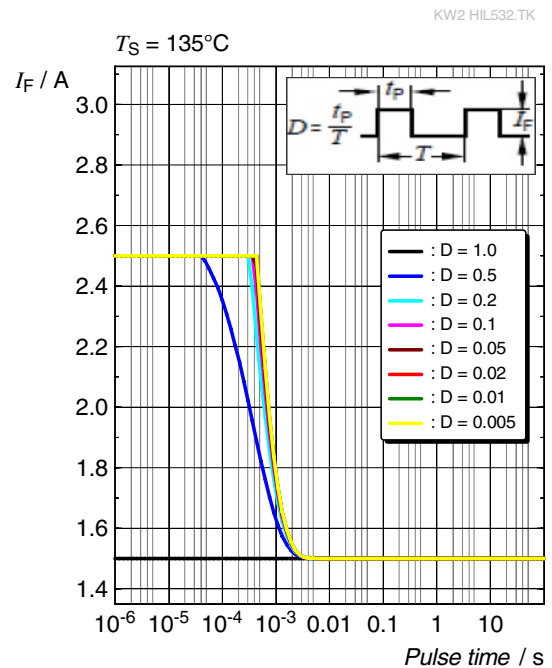
### Permissible Pulse Handling Capability

$I_F = f(t_p)$ ; D: Duty cycle



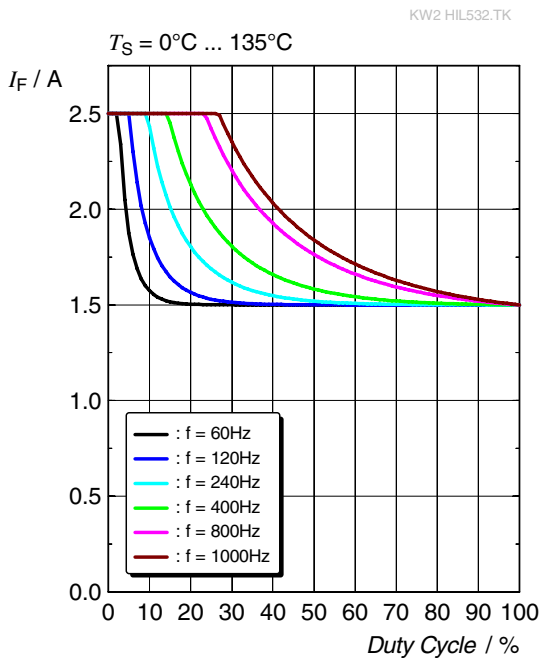
### Permissible Pulse Handling Capability

$I_F = f(t_p)$ ; D: Duty cycle



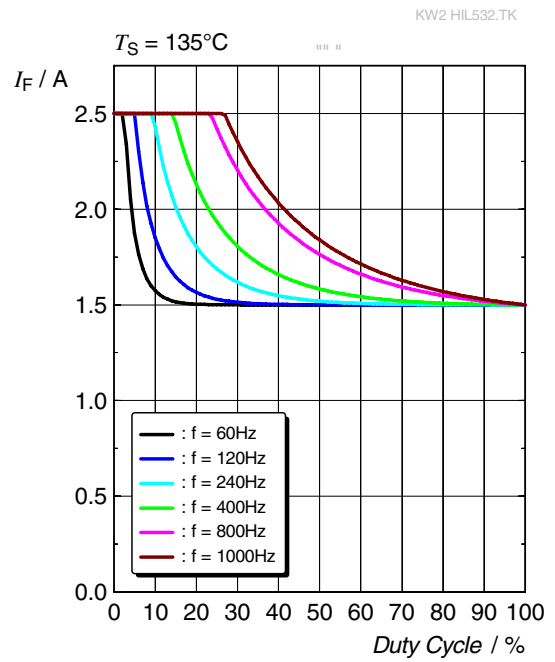
### Permissible F. Handling Capability

f: Frequency

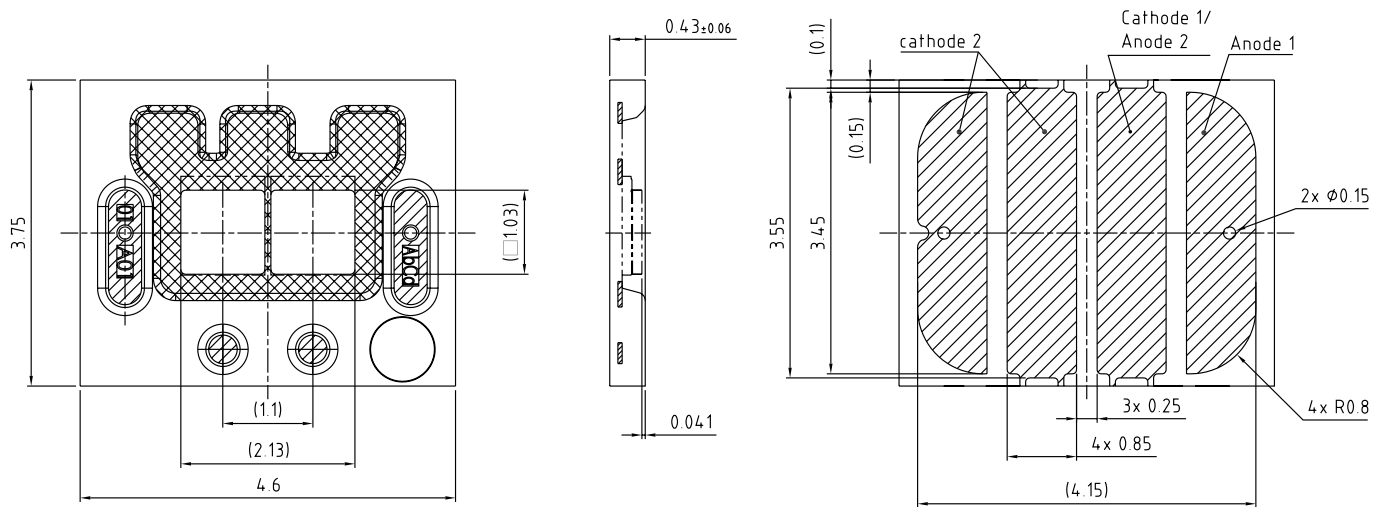


### Permissible F. Handling Capability

f: Frequency



**Dimensional Drawing** <sup>9)</sup>



C63062-A4370-A1-06

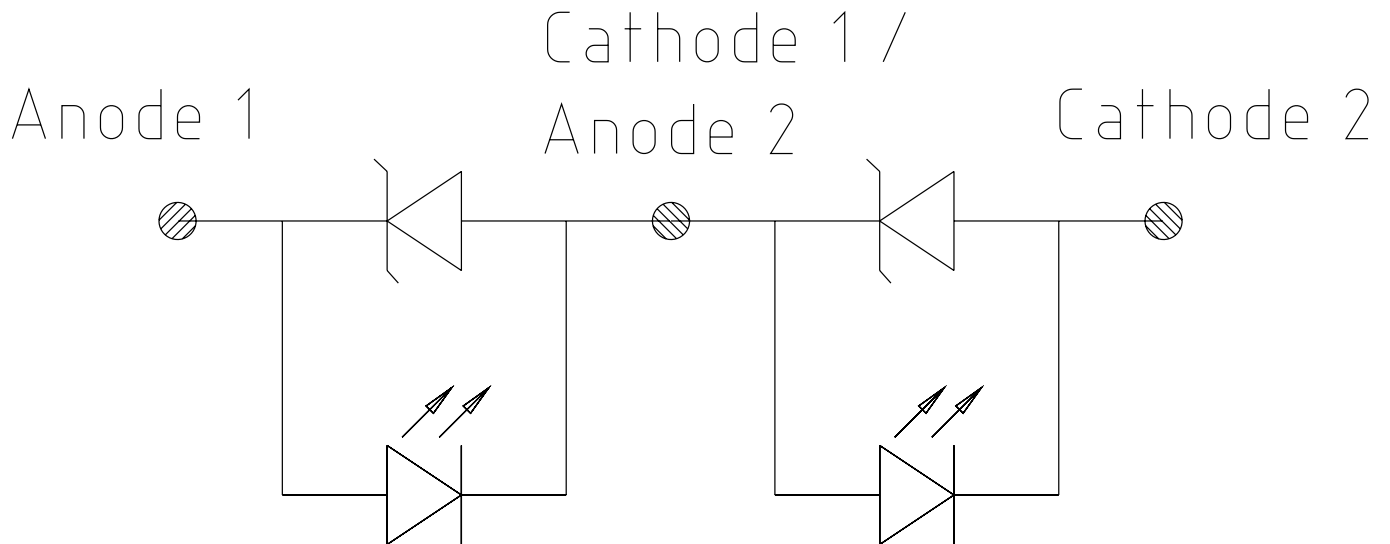
**Further Information:**

**Approximate Weight:** 27.0 mg

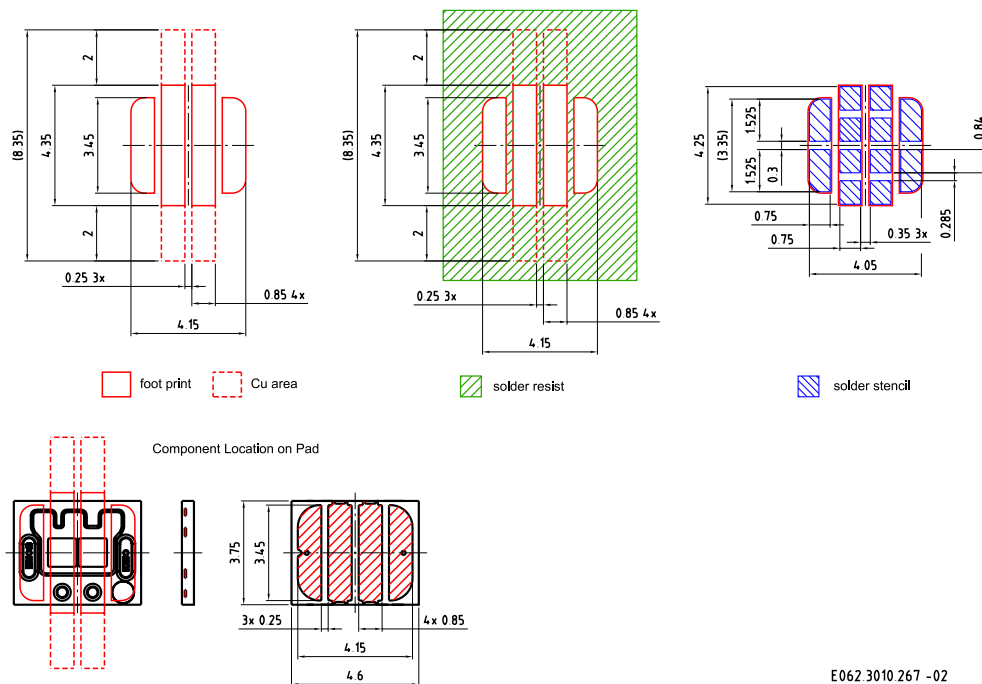
**Corrosion test:** Class: 3B  
 Test condition: 40°C / 90 % RH / 15 ppm H<sub>2</sub>S / 14 days (stricter than IEC 60068-2-43)

**ESD advice:** The device is protected by ESD device which is connected in parallel to the Chip.

## Electrical Internal Circuit



## Recommended Solder Pad <sup>9)</sup>

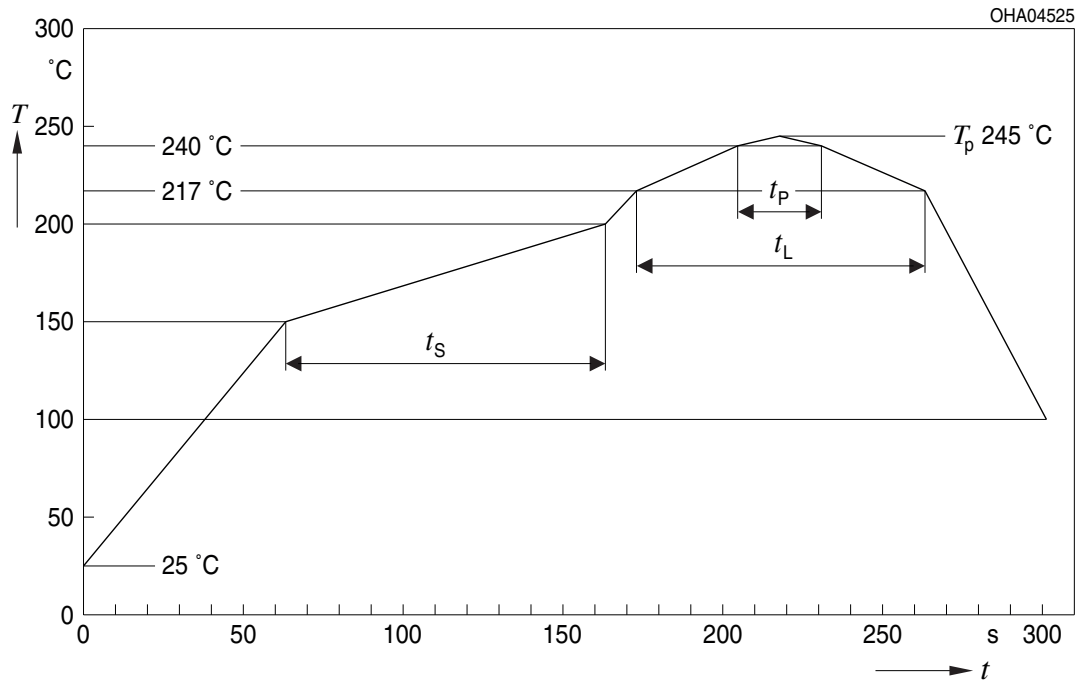


E062.3010.267 -02

For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for any kind of wet cleaning or ultrasonic cleaning. To ensure a high solder joint reliability and to minimize the risk of solder joint cracks, the customer is responsible to evaluate the combination of PCB board and solder paste material for his application.

## Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



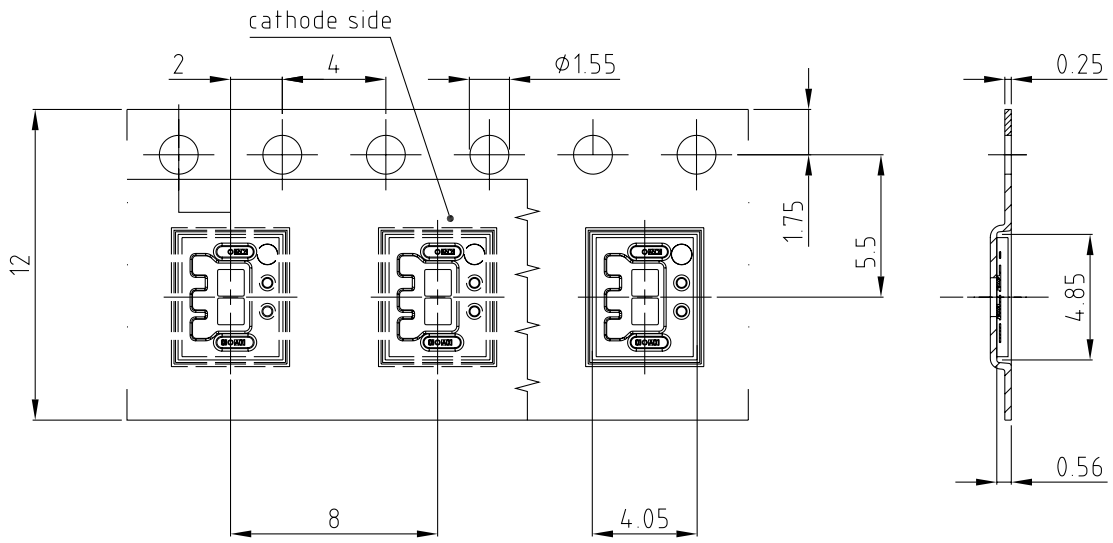
Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat <sup>*)</sup> 25 °C to 150 °C			2	3	K/s
Time $t_s$ $T_{Smin}$ to $T_{Smax}$	$t_s$	60	100	120	s
Ramp-up rate to peak <sup>*)</sup> $T_{Smax}$ to $T_p$			2	3	K/s
Liquidus temperature	$T_L$		217		°C
Time above liquidus temperature	$t_L$		80	100	s
Peak temperature	$T_p$		245	260	°C
Time within 5 °C of the specified peak temperature $T_p - 5$ K	$t_p$	10	20	30	s
Ramp-down rate* $T_p$ to 100 °C			3	6	K/s
Time 25 °C to $T_p$				480	s

All temperatures refer to the center of the package, measured on the top of the component

\* slope calculation  $DT/Dt$ :  $Dt$  max. 5 s; fulfillment for the whole T-range

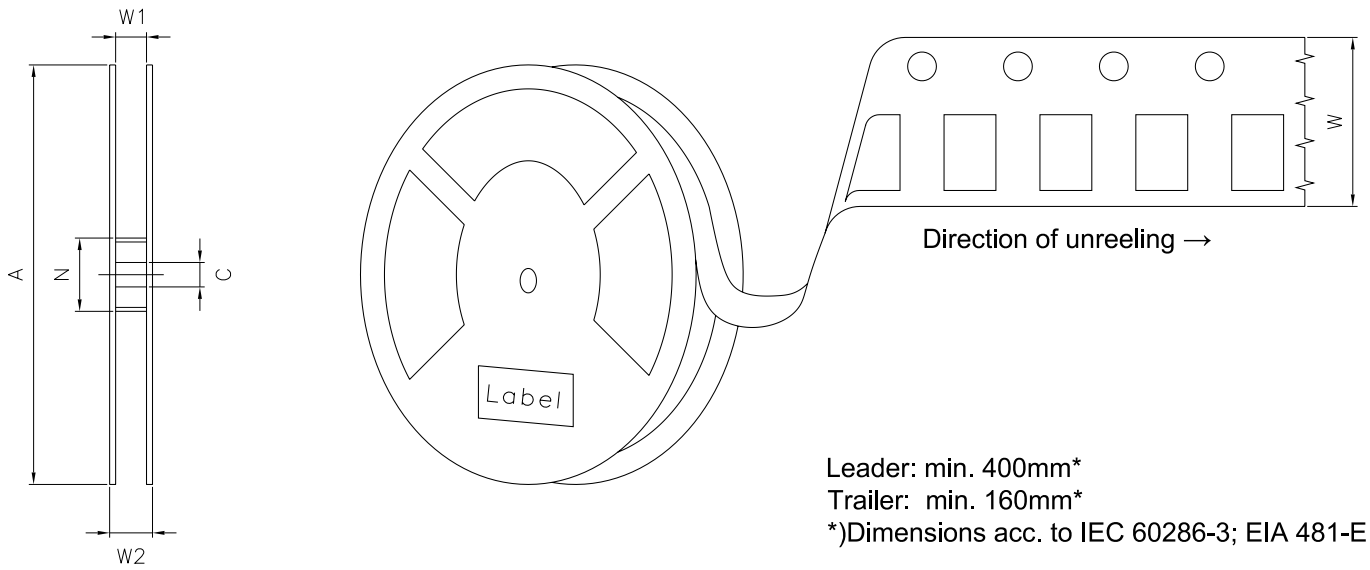


**Taping** <sup>9)</sup>



C67062-A4370-B11-06

**Tape and Reel** <sup>10)</sup>



**Reel Dimensions**

A	W	N <sub>min</sub>	W <sub>1</sub>	W <sub>2max</sub>	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	2000

## Barcode-Product-Label (BPL)

**OSRAM Opto Semiconductors** LX XXXX    BIN1: XX-XX-X-XXX-X


RoHS Compliant

(6P) BATCH NO: 1234567890 ML Temp    ST  
X    XXX °C X

(1T) LOT NO: 1234567890 (9D) D/C: 1234

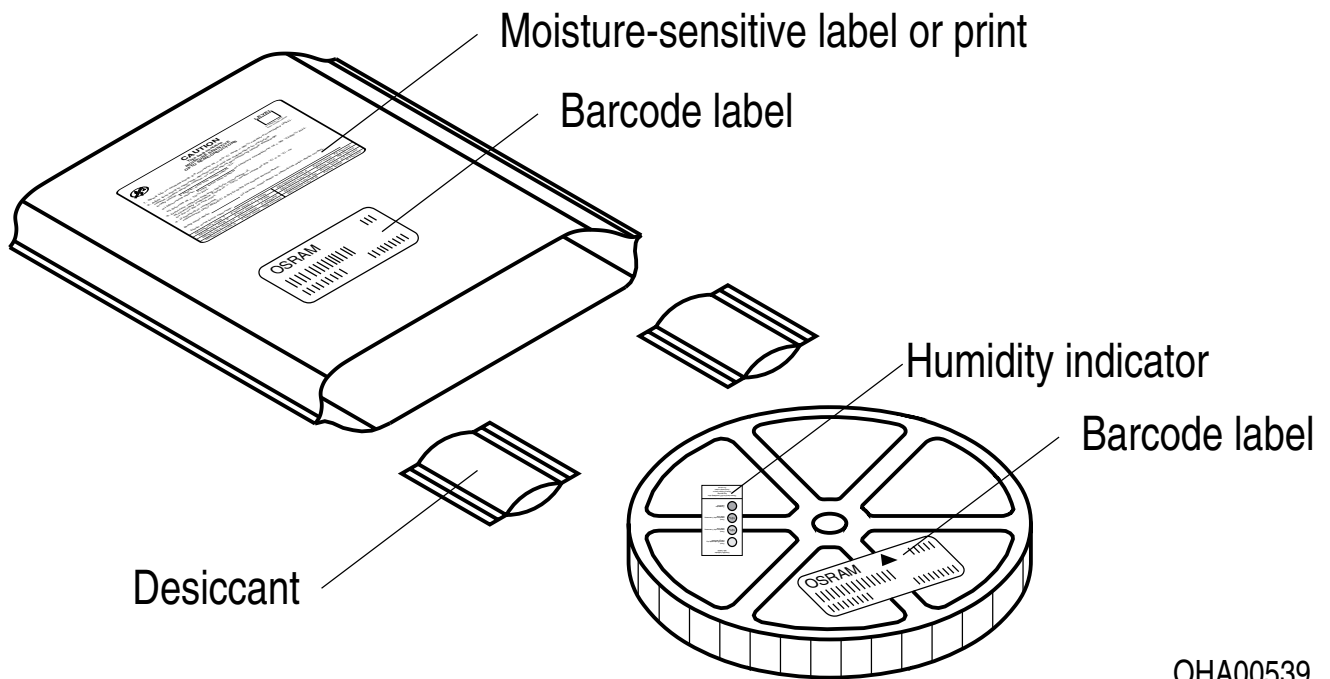
(X) PROD NO: 123456789(Q)QTY: 9999 (G) GROUP: XX-XX-X-X

Pack: RXX  
DEMY    XXX  
X\_X123\_1234.1234 X



OHA04563

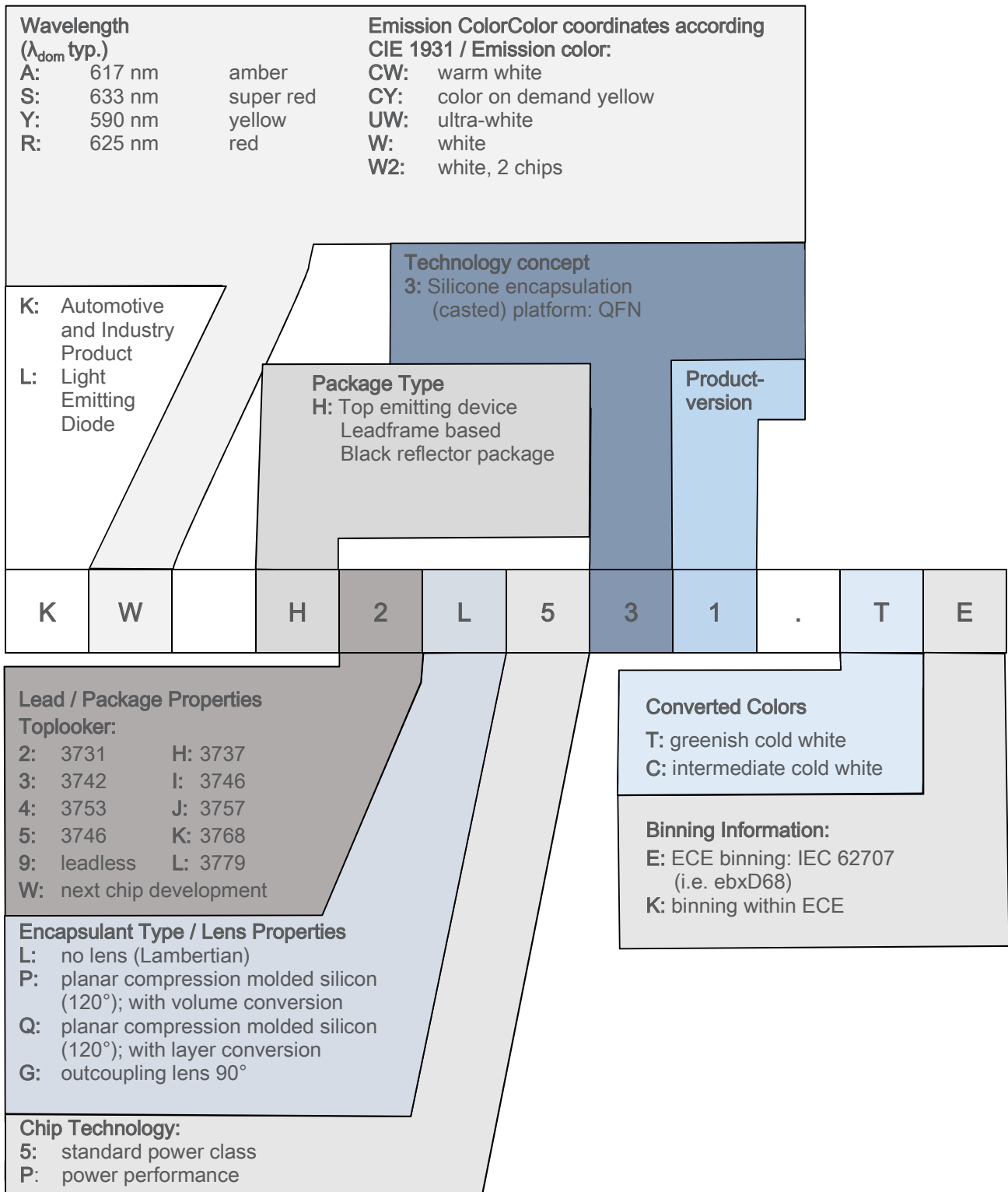
## Dry Packing Process and Materials <sup>9)</sup>



OHA00539

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

## Type Designation System



## Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **moderate risk (exposure time 0.25 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit [www.osram-os.com/appnotes](http://www.osram-os.com/appnotes)

## Disclaimer

### **Attention please!**

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

### **Product and functional safety devices/applications or medical devices/applications**

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.

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## Glossary

- 1) **Brightness:** Brightness values are measured during a current pulse of typically 1 ms, with an internal reproducibility of  $\pm 8\%$  and an expanded uncertainty of  $\pm 11\%$  (acc. to GUM with a coverage factor of  $k = 3$ ).
- 2) **Operating Temperature:** The Operating Temperature  $T_{op}$  is referenced to the Solderpoint  $T_s$  of this device. Proper current derating must be observed to maintain junction temperature below the maximum.
- 3) **Reverse Operation:** Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- 4) **Chromaticity coordinate groups:** Chromaticity coordinates are measured during a current pulse of typically 1 ms, with an internal reproducibility of  $\pm 0.005$  and an expanded uncertainty of  $\pm 0.01$  (acc. to GUM with a coverage factor of  $k = 3$ ).
- 5) **Forward Voltage:** The forward voltage is measured during a current pulse of typically 1 ms, with an internal reproducibility of  $\pm 0.05\text{ V}$  and an expanded uncertainty of  $\pm 0.1\text{ V}$  (acc. to GUM with a coverage factor of  $k = 3$ ).
- 6) **Thermal Resistance:**  $R_{th\ max}$  is based on statistic values ( $6\sigma$ ).
- 7) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 8) **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- 9) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with  $\pm 0.1$  and dimensions are specified in mm.
- 10) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

## Revision History

Version	Date	Change
1.0	2020-05-06	Initial Version

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